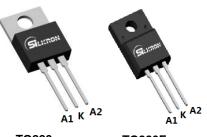
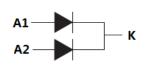


Main Product Characteristics:

IF	30A
VRRM	60V
T _j (max)	150 ℃
Vf(max)	0.65V





TO220 TO220F SSMD3060CT SSMD3060CTF

Schematic Diagram

Features and Benefits:

- High Junction Temperature
- High ESD Protection
- High Forward & Reverse Surge capability



Description:

Schottky Barrier Rectifier designed for high frequency switch model power supplies such as adaptors and DC/DC convertors; this product special design for high forward and reverse surge capability

Absolute Rating:

Symbol	Characterizes	Value	Unit
V_{RRM}	Peak Repetitive Reverse Voltage	60	V
$V_{R(RMS)}$	RMS Reverse Voltage	42	V
I _{F(AV)}	Average Forward Current	30	Α
I _{FSM}	Non Repetitive Surge Forward Current(tp=8.3ms sinusoidal)	200	Α
I _{RRM}	Peak Repetitive Reverse Surge Current(Tp=2us)	2	А
T_J	Maximum operation Junction Temperature Range	-55~150	$^{\circ}\!\mathbb{C}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}\!\mathbb{C}$

Thermal Resistance

Symbol	Characterizes	Value	Unit	
$R_{ heta JC}$	Maximum Thermal Resistance Junction To	2	°C/W	
R _{θJC}	Case(per leg)	TO220F	4	°C/W

Electrical Characterizes @T_A=25℃ unless otherwise specified

Symbol	Characterizes	Min	Тур	Max	Unit	Test Condition
V_R	Reverse Breakdown Voltage	60			٧	I _R =0.5mA
V Familiard Voltage Draw				0.65	W	I _F =15A, T _J =25℃
V_{F}	Forward Voltage Drop			0.6	V	I _F =15A, T _J =125℃
I _R	Leakage Current			0.2	mΛ	V _R =60V, T _J =25°C
				100	mA	V _R =60V, T _J =125℃

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I-V Curves:

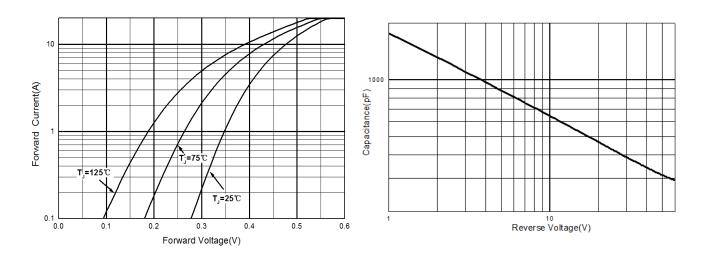


Figure 1: Typical Forward Characteristics Figure 2: Typical Capacitance Characteristics

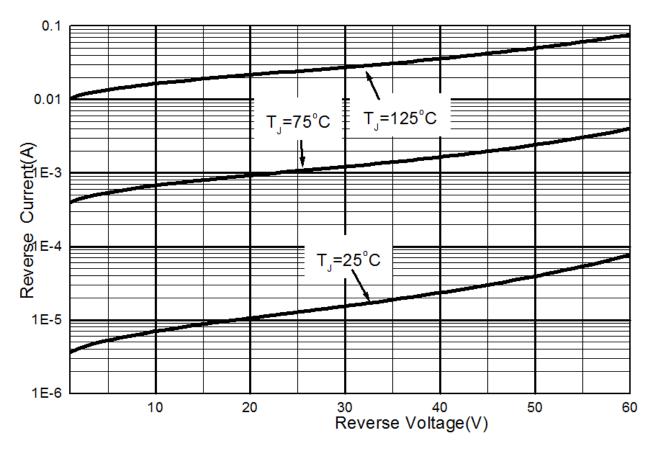
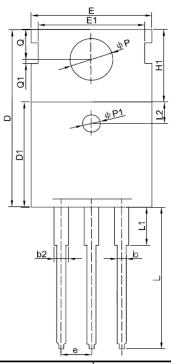


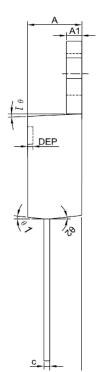
Figure 3: Typical Reverse Characteristics

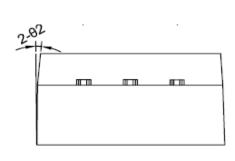




Mechanical Data: TO220:





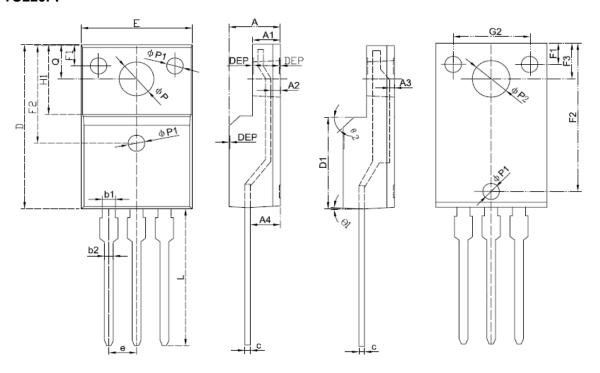


Cumbal	Dime	ension In Millim	eters	Dimension In Inches			
Symbol	Min	Nom	Max	Min	Nom	Max	
Α	4.400	4.550	4.700	0.173	0.179	0.185	
A1	1.270	1.300	1.330	0.050	0.051	0.052	
A2	2.590	2.690	2.790	0.102	0.106	0.110	
b	0.770	-	0.900	0.030	-	0.035	
b2	1.230	-	1.360	0.048	-	0.054	
С	0.480	0.500	0.520	0.019	0.020	0.020	
D	15.100	15.400	15.700	-	0.606	-	
D1	9.000	9.100	9.200	0.354	0.358	0.362	
DEP	0.050	0.285	0.520	0.002	0.011	0.020	
Е	10.060	10.160	10.260	0.396	0.400	0.404	
E1	-	8.700	-	-	0.343	-	
ФР1	1.400	1.500	1.600	0.055	0.059	0.063	
е		2.54BSC 0.1BSC					
e1		5.08BSC		0.2BSC			
H1	6.100	6.300	6.500	0.240	0.248	0.256	
L	12.750	12.960	13.170	0.502	0.510	0.519	
L1	-	-	3.950	-	-	0.156	
L2		1.85REF			0.073REF		
ФР	3.570	3.600	3.630	0.141	0.142	0.143	
Q	2.730	2.800	2.870	0.107	0.110	0.113	
Q1	-	0.200	-	-	0.008	-	
0 1	5°	7 ⁰	9º	5°	7°	9º	
Θ2	1 ⁰	3 ⁰	5°	10	3 ⁰	5 ⁰	

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TO220F:



Cumbal	Dimension In Millimeters			Dimension In Inches			
Symbol	Min	Nom	Max	Min	Nom	Max	
E	9.960	10.160	10.360	0.392	0.400	0.408	
Α	4.500	4.700	4.900	0.177	0.185	0.193	
A1	2.340	2.540	2.740	0.092	0.100	0.108	
A2	0.950	1.050	1.150	0.037	0.041	0.045	
A3	0.420	0.520	0.620	0.017	0.020	0.024	
A4	2.650	2.750	2.850	0.104	0.108	0.112	
С	-	0.500	-	-	0.020	-	
D	15.670	15.870	16.070	0.617	0.625	0.633	
Q	3.200	3.300	3.400	0.126	0.130	0.134	
H1	6.480	6.680	6.880	0.255	0.263	0.271	
е	2.54BSC			0.10BSC			
ФР	-	3.183	-	-	0.125	-	
L	12.780	12.980	13.180	0.503	0.511	0.519	
D1	8.990	9.190	9.390	0.354	0.362	0.370	
ФР1	1.400	1.500	1.600	0.055	0.059	0.063	
ФР2	-	3.450	-	-	0.136	-	
0 1	4°	5°	6°	4°	5°	6°	
Θ2	-	45°	-	-	45°	-	
DEP	0.050	0.100	0.150	0.002	0.004	0.006	
F1	1.900	2.000	2.100	0.075	0.079	0.083	
F2	8.980	9.180	9.380	0.354	0.361	0.369	
F3	3.200	3.300	3.400	0.126	0.130	0.134	
G2	6.900	7.000	7.100	0.272	0.276	0.280	
b1	1.170	1.205	1.240	0.046	0.047	0.049	
b2	0.770	0.810	0.850	0.030	0.032	0.033	



Ordering and Marking Information

Device Marking: SSMD3060CT&SSMD3060CTF

Package (Available)
TO-220&TO220F
Operating Temperature Range
C:-55 to 150 °C

Devices per Unit

Package Type	Units/ Tube	Tubes/Inner Box	Units/Inner Box	Inner Boxes/Carton Box	Units/Car ton Box
TO220	50	20	1000	6	6000
TO220F	50	20	1000	6	6000

Reliability Test Program

Test Item	Conditions	Duration	Sample Size
High	Tj=125℃ to 150℃ @	168 hours	3 lots x 77 devices
Temperature	80% of Max	500 hours	
Reverse	VDSS/VCES/VR	1000 hours	
Bias(HTRB)			

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